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Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) Silicon NPN Epitaxial Type (PCT Process)

HN4B04J

Audio Frequency General Purpose Amplifier Applications Driver Stage Amplifier Applications Switching application

Q1:

- Excellent h_{FE} linearity
 - : $h_{FE(2)}$ =25 (min) at V_{CE} = -6V, I_C = -400mA

Q2:

- Excellent h_{FE} linearity
 - : h_{FE(2)} =25 (min) at V_{CE} = 6V, I_C = 400mA

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-35	V
Collector-emitter voltage	V _{CEO}	-30	V
Emitter-base voltage	V _{EBO}	-5	/ //
Collector current	IC	-500	mA



Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	VCBO	35	\sim v
Collector-emitter voltage	V _{CEO} <	30	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	Ic	500	mA

Q1,Q2 Common Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector power dissipation	Pe*	300	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

*Total rating. Power dissipation per element should not exceed 200mW.

Start of commercial production 2000-06

Q1 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	—	V_{CB} = -35V, I _E = 0	_	_	-100	nA
Emitter cut-off current	I _{EBO}	_	$V_{EB} = -5V, I_C = 0$			-100	nA
DC current gain	h _{FE(1)}	—	V _{CE} = -1V, I _C = -100mA	70		240	
	h _{FE(2)}	—	$V_{CE} = -6V, I_C = -400mA$	25	7		
Collector-emitter saturation voltage	V _{CE (sat)}	_	I _C = -100mA, I _B = -10mA	J)	/_0.1	-0.25	V
Base-Emitter Voltage	V _{BE}	_	V _{CE} = -1V, I _C = -100mA	4	-0.8	-1.0	V
Transition frequency	f _T	_	$V_{CE} = -6V, I_C = -20mA$	Z	200		MHz
Collector output capacitance	C _{ob}	_	$V_{CB} = -6V, I_E = 0, f = 1MHz$	-	13		pF

Q2 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I _{CBO}	_	$V_{CB} = 35V, I_E = 0$	R	L)	100	nA
Emitter cut-off current	I _{EBO}	—	$V_{EB} = 5V, I_C = 0$			100	nA
DC current gain	h _{FE(1)}	_ <	V _{CE} = 1V, I _C = 100mA	70	-	240	
	h _{FE(2)}	$\left(\right)$	V _{GE} = 6V, I _C = 400mA	25	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}		I _C = 100mA, I _B = 10mA	/	0.1	0.25	V
Base-Emitter Voltage	V _{BE}	X	V _{CE} = 1V, I _C = 100mA		0.8	1.0	V
Transition frequency	fT	$\langle \cdot \rangle$	V _{CE} = 6V, I _C = 20mA	-	300	-	MHz
Collector output capacitance	C _{ob}	Ĵ	V _{CB} = 6V, I _E = 0, f = 1MHz	_	7	_	pF

Marking

Equivalent Circuit (Top View)



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Q1 (PNP transistor)



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Q2 (NPN transistor)



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(Q1,Q2 Common)



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